NSN 5962-01-321-9015



Memory Microcircuit - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5962-01-321-9015 **Overall Length:** 1.490 inches **Overall Height:** 0.432 inches Overall Width: 0.620 inches **Body Length:** 1.490 inches **Body Width:** 0.610 inches **Body Height:** 0.217 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius **Storage Tempurature Range:** -65.0/+150.0 degrees celsius **Features Provided:** Burn in and electrostatic sensitive and programmed and ultraviolet erasable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** N-type metal oxide-semiconductor logic **Input Circuit Pattern:** 16 input **Case Outline Source And Designator:** D-10 mil-m-38510 **Terminal Surface Treatment:** Voltage Rating And Type Per Characteristic: 7.0 volts power source **Time Rating Per Chacteristic:**

Memory Device Type:

Rom

output

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

200.00 nanoseconds propagation delay time, low to high level output and 200.00 nanoseconds propagation delay time, high to low level

Terminal Type And Quantity:

28 printed circuit

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N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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